



# *Semiconductor Memory Organization & Addressing*

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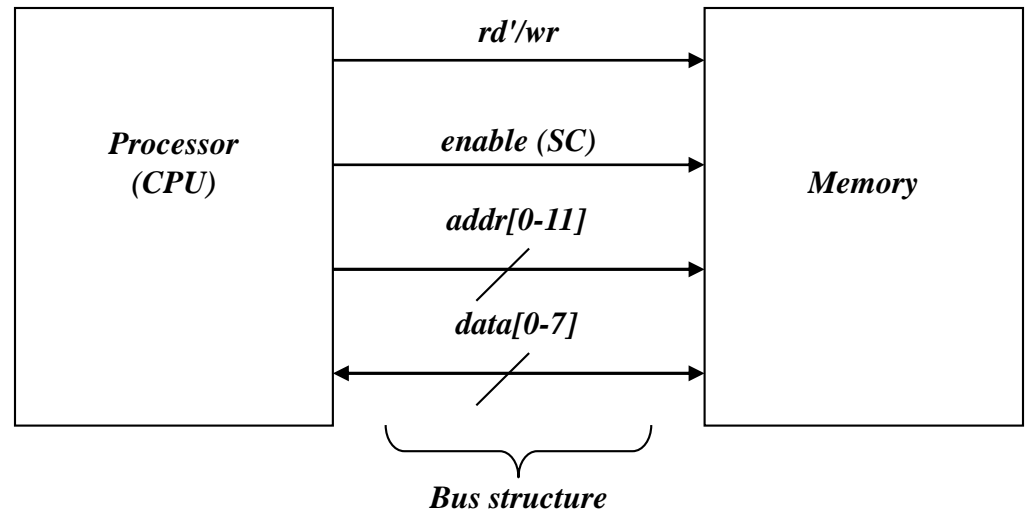


Facultad  
de Matemática,  
Astronomía, Física  
y Computación

# Introduction

- Computer systems functionality aspects
  - Processing
    - Transformation of data
    - Implemented using processors
  - Storage
    - Retention of data
    - Implemented using memory
  - Communication
    - Transfer of data between processors and memories
    - Implemented using buses
    - Called *interfacing*

# A simple bus



## □ Wires:

- Uni-directional or bi-directional
- One line may represent multiple wires

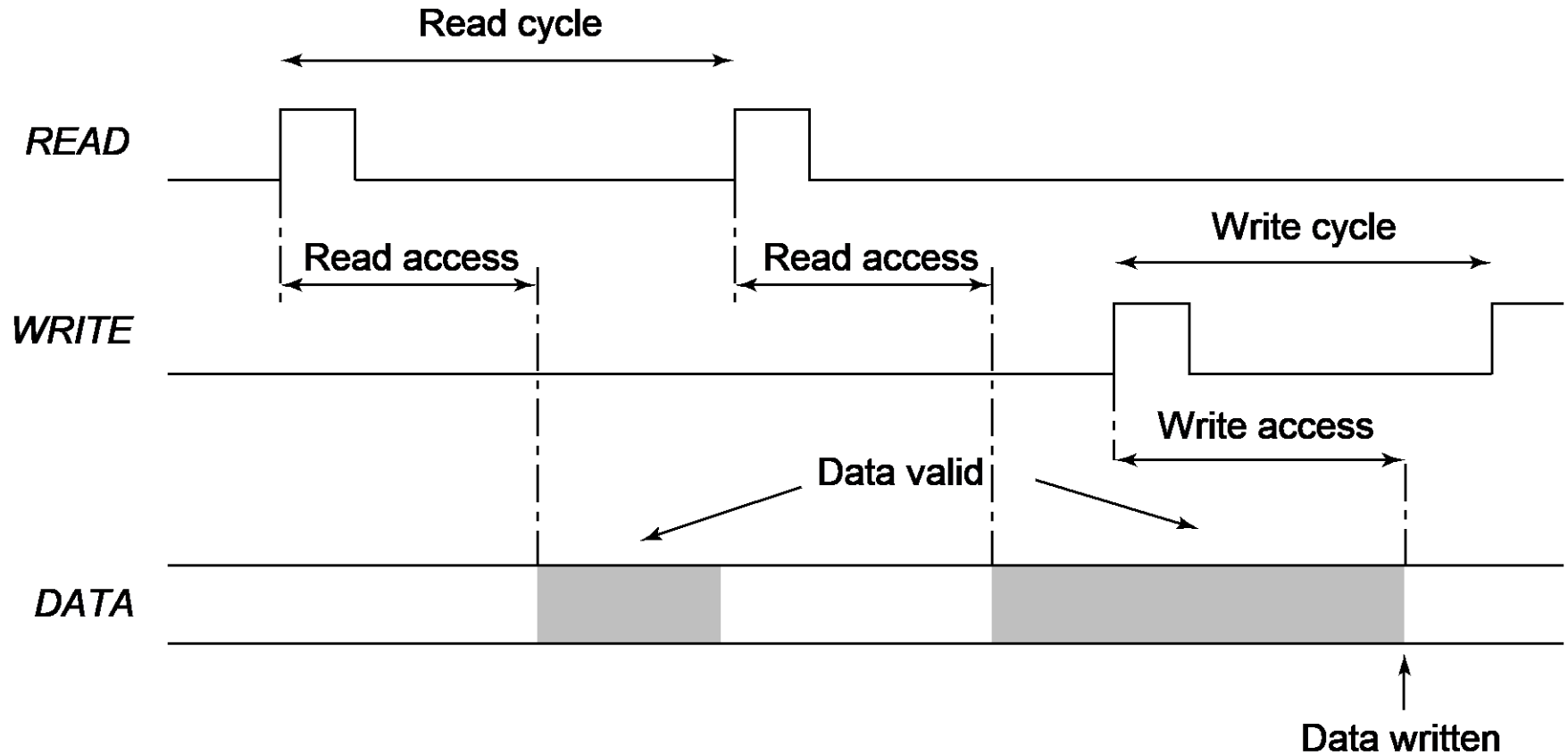
## □ Bus

- Set of wires with a single function
  - Address bus, data bus
- Or, entire collection of wires
  - Address, data and control
  - Associated protocol: rules for communication

# Semiconductor Memory Classification

Read-Write Memory		Non-Volatile Read-Write Memory	Read-Only Memory
Random Access	Non-Random Access	EPROM E <sup>2</sup> PROM  FLASH	Mask-Programmed Programmable (PROM)
SRAM  DRAM	FIFO  LIFO  Shift Register  CACHE		

# Memory Timing: Definitions



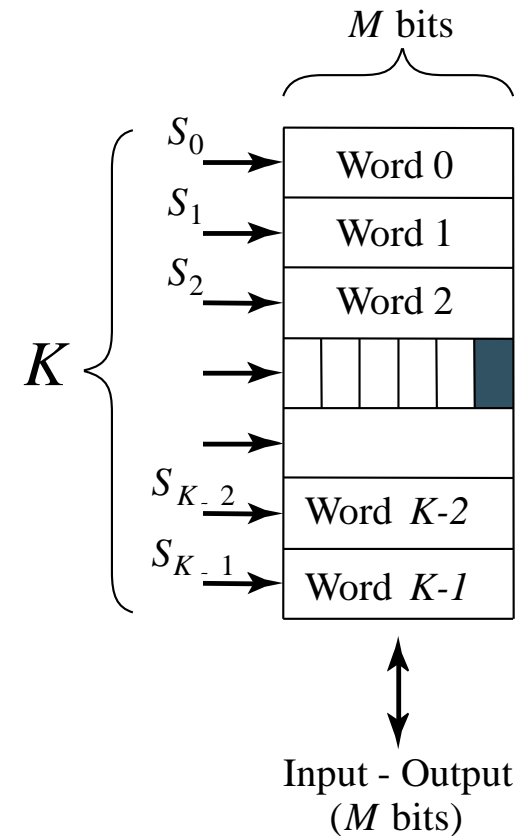
# Memory Organization

Memory Address		Word (8 bits)							
Binary	Dec								
0000000000	0	0	1	1	1	0	0	1	0
0000000001	1	1	1	1	1	1	1	1	1
0000000010	2	0	0	0	1	0	0	1	1
.	.	.	.	.	.	.	.	.	.
.	.	.	.	.	.	.	.	.	.
1111111101	1021	1	1	1	1	0	0	0	1
1111111110	1022	1	1	0	0	0	0	0	0
1111111111	1023	0	0	0	0	1	1	1	1

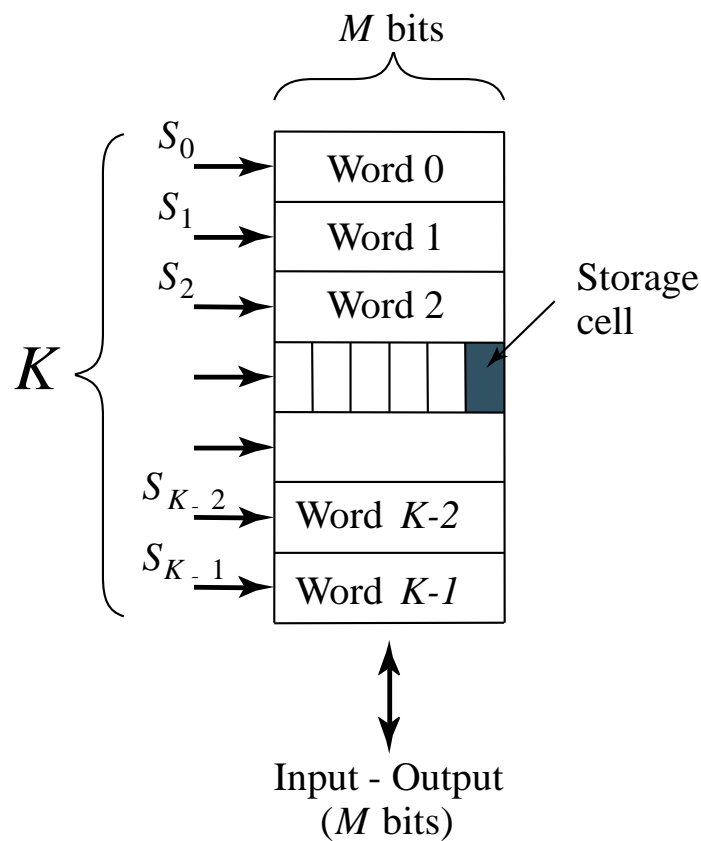
Addressed word

Storage bit cell

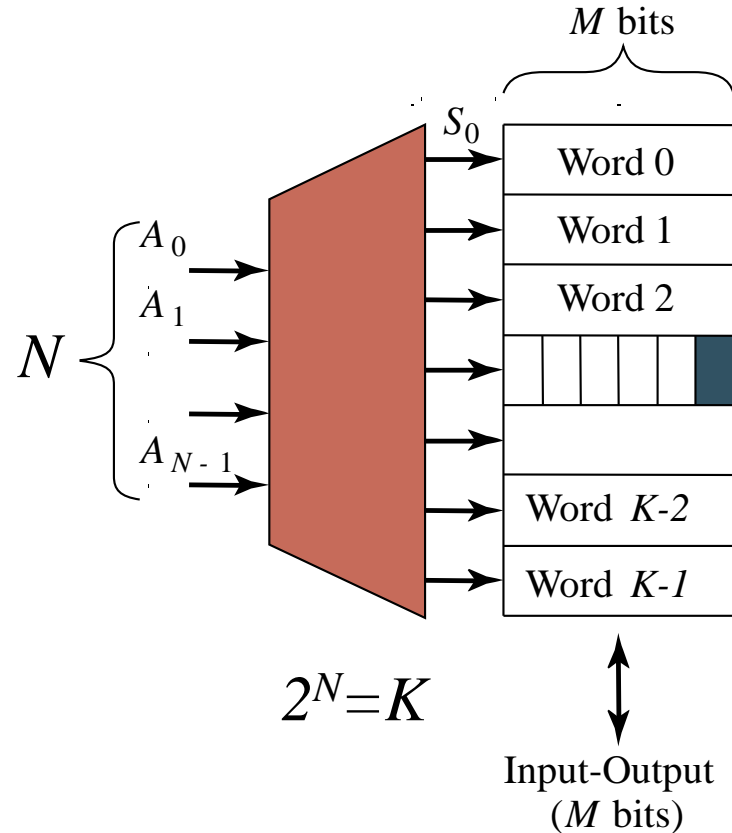
**Example organization for  
1Kword x 8 bits = 8K bits memory**



# Memory Architecture: Decoders



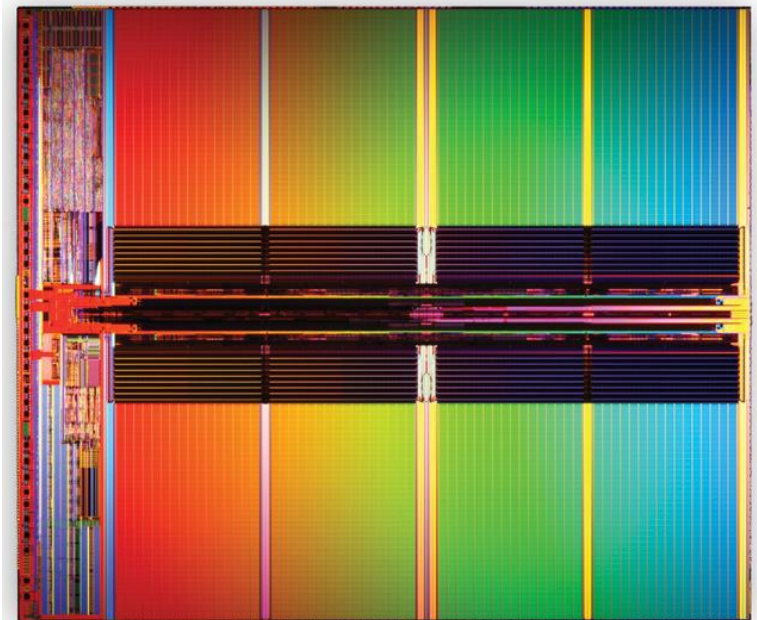
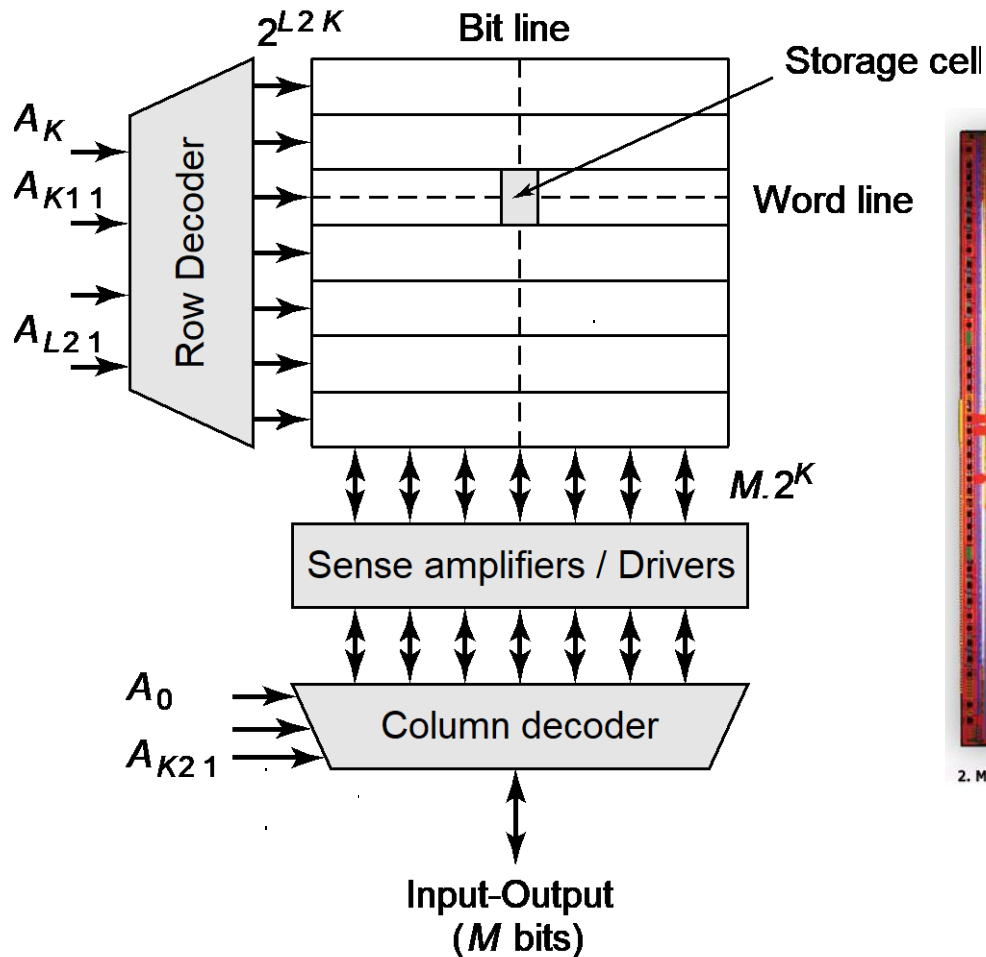
Intuitive architecture for  $K \times M$  memory  
 Too many select signals:  
 $K$  words ==  $K$  select signals



Decoder reduces the number of select signals  
 $N = \log_2 K$

# Array-Structured Memory Architecture

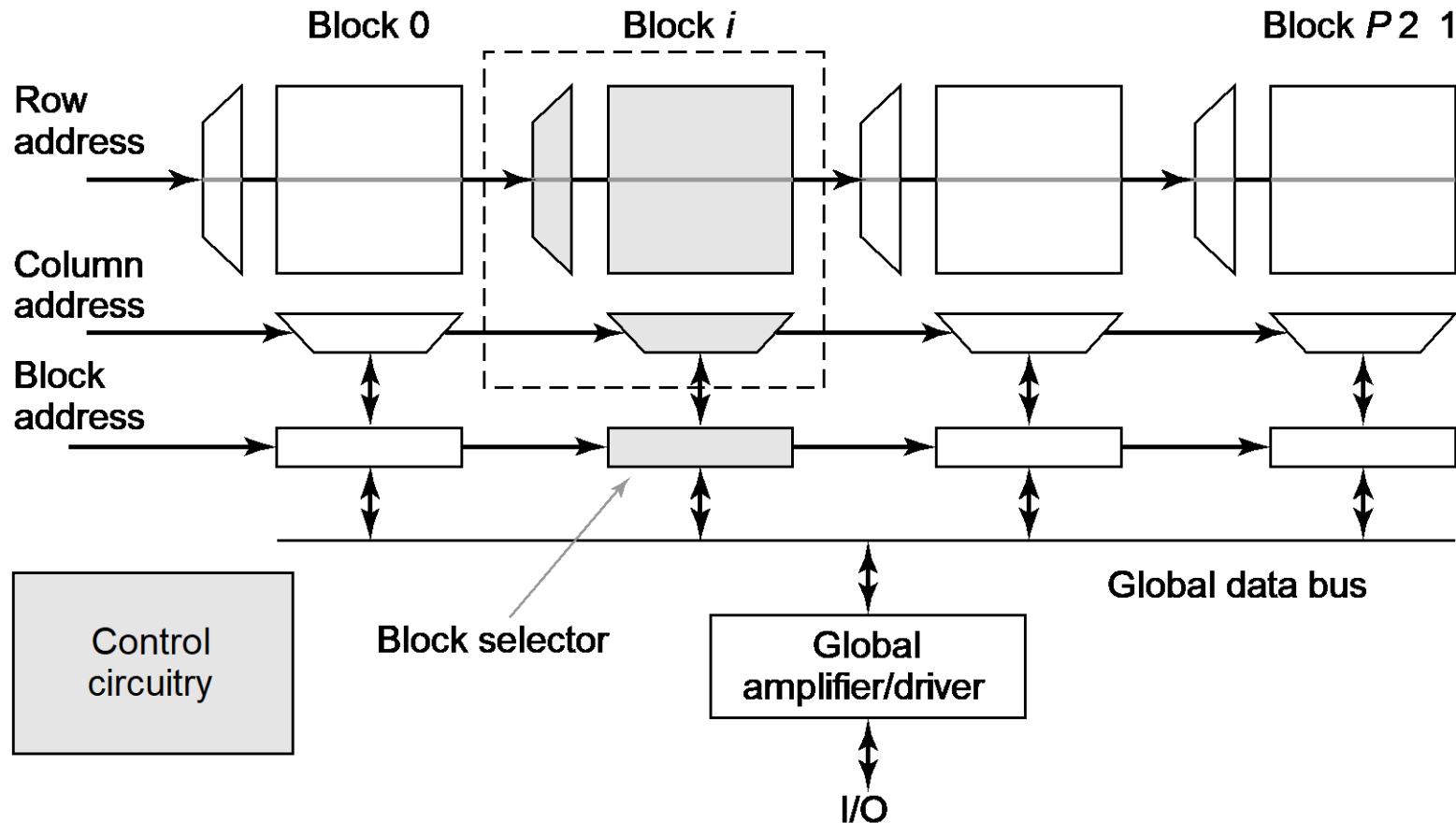
Problem: ASPECT RATIO or HEIGHT  $\gg$  WIDTH



2. Micron's triple-level cell (TLC) flash memory stores 3 bits of data in each transistor.



# Hierarchical Memory Architecture

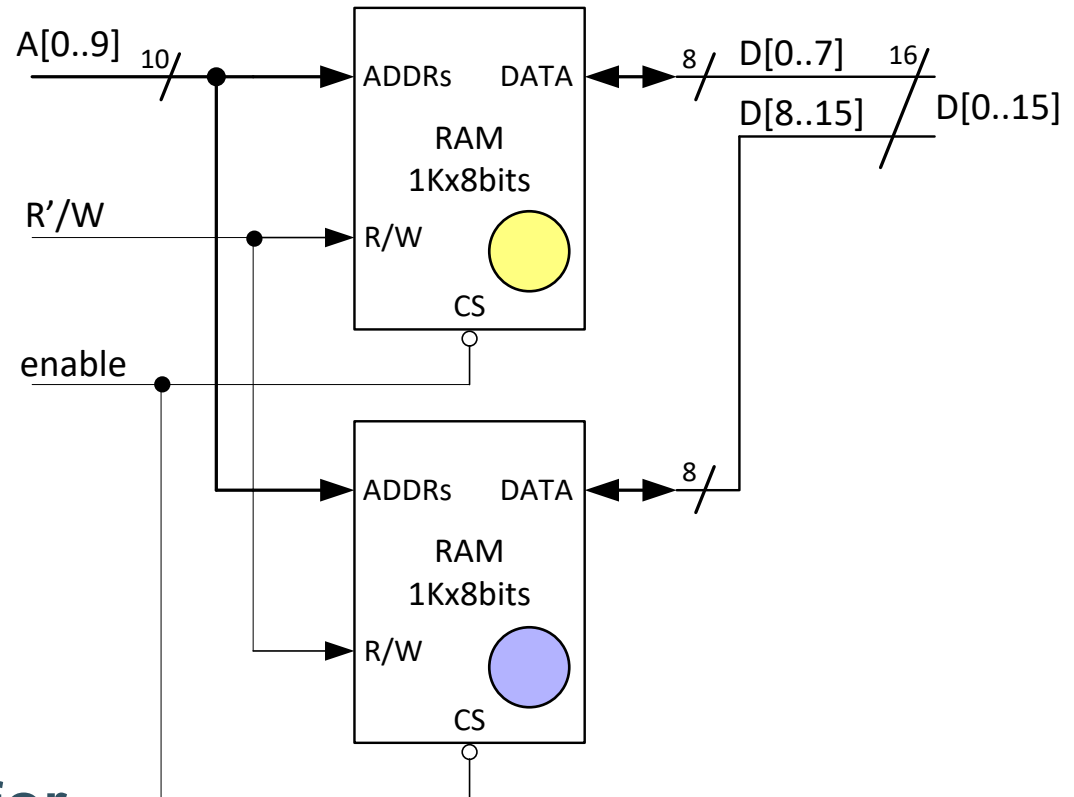


## Advantages:

1. Shorter wires within blocks
2. Block address activates only 1 block => power savings

# Memory Addressing (parallel)

A <sub>9</sub> . . . A <sub>0</sub>	D <sub>15</sub> . . . D <sub>8</sub>	D <sub>7</sub> . . . D <sub>0</sub>
0000000000	0 1 . 1	0 . 1 0
0000000001	1 1 . 1	1 . 1 1
0000000010	0 0 . 1	0 . 1 1
	. . . .	. . . .
	. . . .	. . . .
	. . . .	. . . .
1111111101	1 1 . 1	0 . 0 1
1111111110	1 1 . 0	0 . 0 0
1111111111	0 0 . 0	1 . 1 1

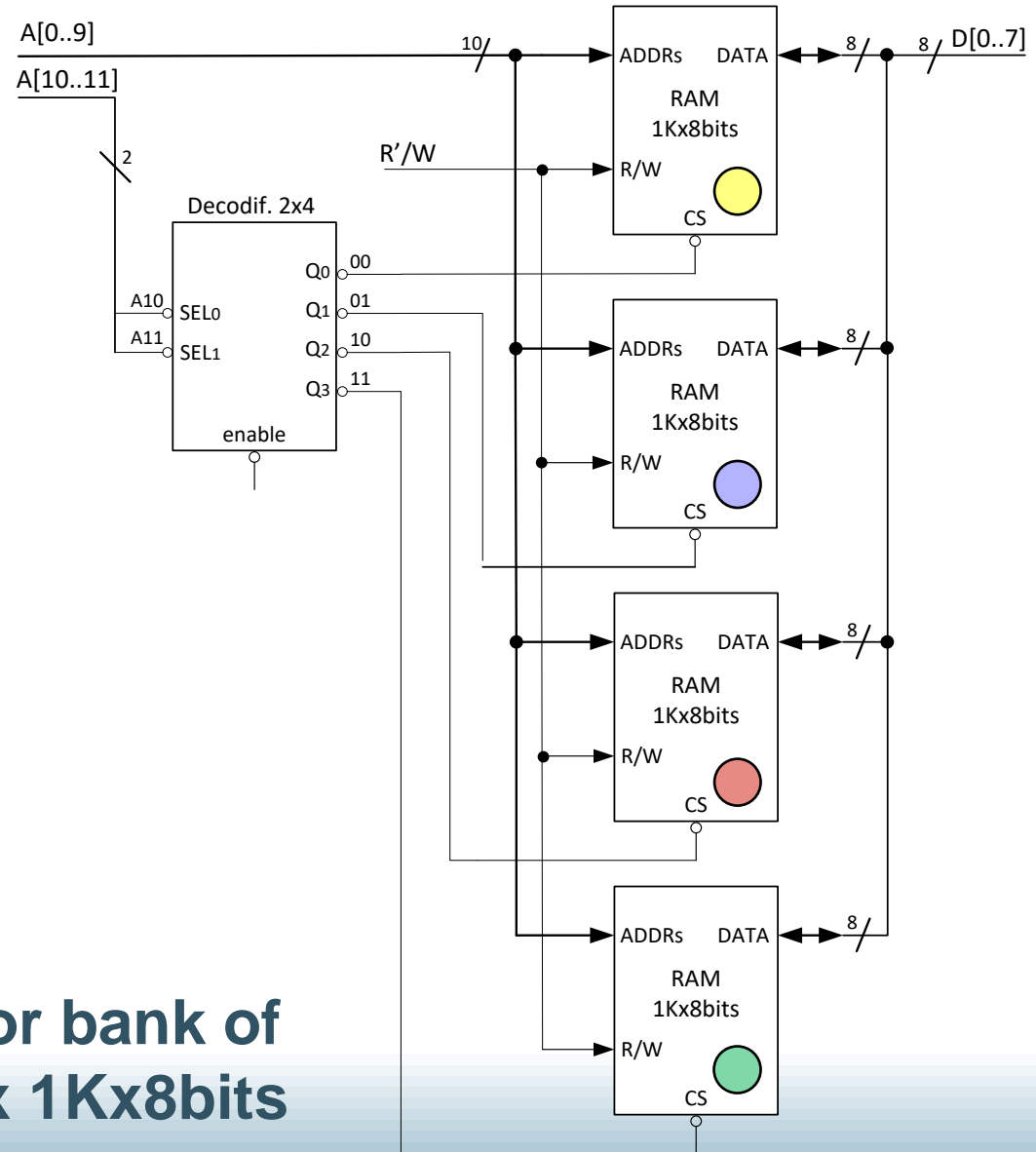


**Example organization for  
bank of 1Kword x 16 bits  
from 2 x 1Kx8bits**

# Memory Addressing (serial)

A <sub>11</sub>	A <sub>10</sub>	A <sub>9</sub>	...	A <sub>0</sub>	D <sub>7</sub>	...	D <sub>0</sub>
0	0	0	0	0	0	1	1
0	0	0	0	0	0	0	0
0	0	1	1	1	1	1	1
0	1	0	0	0	0	0	0
0	1	0	0	0	0	0	0
0	1	1	1	1	1	1	1
1	0	0	0	0	0	0	0
1	0	0	0	0	0	0	0
1	0	1	1	1	1	1	1
1	1	0	0	0	0	0	0
1	1	0	0	0	0	0	0
1	1	1	1	1	1	1	1

**Example organization for bank of 4Kword x 8 bits from 4 x 1Kx8bits**



# *Example: Conventional PC Memory map*

